

## 3 V/5 V CMOS 0.5 Ω SPDT/2:1 Mux in SC70

### ADG849

#### FEATURES

Ultralow on-resistance: 0.5 Ω typical 0.8 Ω maximum at 5 V supply Excellent audio performance, ultralow distortion: 0.13 Ω typical 0.24 Ω maximum R<sub>ON</sub> flatness High current carrying capability: 400 mA continuous current 600 mA peak current at 5 V Automotive temperature range: -40°C to +125°C Rail-to-rail operation Typical power consumption (<0.01 µW) Pin-compatible upgrade for the ADG749 and ADG779

# SUITCHES SHOWN FOR A LOGIC 1 INPUT

FUNCTIONAL BLOCK DIAGRAM

Figure 1.

#### **APPLICATIONS**

Cellular phones PDAs Battery-powered systems Audio and video signal routing Modems PCMCIA cards Hard drives Relay replacement

#### **GENERAL DESCRIPTION**

The ADG849 is a monolithic, CMOS SPDT (single pole, double throw) switch that operates with a supply range of 1.8 V to 5.5 V. It is designed to offer ultralow on-resistance values of typically 0.5  $\Omega$ . This design makes the ADG849 an ideal solution for applications that require minimal distortion through the switch. The ADG849 also has the capability of carrying large amounts of current, typically 600 mA at 5 V operation.

Each switch of the ADG849 conducts equally well in both directions when on. The device exhibits break-before-make switching action, thus preventing momentary shorting when switching channels.

The ADG849 is available in a tiny, 6-lead SC70 package, making it the ideal candidate for space-constrained applications.

#### **PRODUCT HIGHLIGHTS**

- 1. Very low on-resistance,  $0.5 \Omega$  typical.
- 2. Tiny, 6-lead SC70 package.
- 3. Low power dissipation. The CMOS construction ensures low power dissipation.
- 4. High current carrying capability.
- 5. Low THD + noise (0.01% typ).

Rev. 0

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### **TABLE OF CONTENTS**

Specifications	3
Absolute Maximum Ratings	5
ESD Caution	5
Pin Configuration and Function Descriptions	6

3	Typical Performance Characteristics7
5	Test Circuits9
5	Outline Dimensions 11
6	Ordering Guide 11

#### **REVISION HISTORY**

7/04—Revision 0: Initial Version

### **SPECIFICATIONS**

Table 1.  $V_{DD}$  = 4.5 V to 5.5 V, GND = 0 V<sup>1</sup>

Parameter	+25°C	–40°C to +85°C	–40°C to +125°C	Unit	Test Conditions/Comments
ANALOG SWITCH					
Analog Signal Range			$0 V$ to $V_{\text{DD}}$	V	
On-Resistance (R <sub>ON</sub> )	0.5			Ωtyp	$V_{s} = 0 V \text{ to } V_{DD}$ , $I_{Ds} = -100 \text{ mA}$
	0.6	0.7	0.8	Ωmax	See Figure 15
On-Resistance Match Between Channels $(\Delta R_{ON})$	0.05			Ωtyp	$V_{\rm S} = 0.85$ V, $I_{\rm DS} = -100$ mA
	0.095	0.11	0.125	Ωmax	
On-Resistance Flatness (R <sub>FLAT(ON)</sub> )	0.13			Ωtyp	$V_{s} = 0 V$ to $V_{DD}$ , $I_{Ds} = -100 \text{ mA}$
	0.18	0.22	0.24	Ωmax	
LEAKAGE CURRENTS					$V_{DD} = 5.5 V$
Source Off Leakage, $I_S$ (Off)	±0.01			nA typ	$V_{S} = 4.5 V/1 V$ , $V_{D} = 1 V/4.5 V$ , see Figure 16
Channel On Leakage, I <sub>D</sub> , I <sub>s</sub> (On)	±0.04			nA typ	$V_{s} = V_{D} = 1 V$ , or $V_{s} = V_{D} = 4.5 V$ , see Figure 17
DIGITAL INPUTS					
Input High Voltage, V <sub>INH</sub>			2.0	V min	
Input Low Voltage, VINL			0.8	V max	
Input Current					
I <sub>INL</sub> or I <sub>INH</sub>	0.005			μA typ	$V_{IN} = V_{INL} \text{ or } V_{INH}$
			±0.1	μA max	
C <sub>IN</sub> , Digital Input Capacitance	2.5			pF typ	
DYNAMIC CHARACTERISTICS <sup>2</sup>					
ton	11			ns typ	$R_L = 50 \Omega$ , $C_L = 35 pF$
	15	17	18	ns max	V <sub>s</sub> = 3 V, see Figure 18
toff	9			ns typ	$R_{L} = 50 \Omega, C_{L} = 35 pF$
	13	14	15	ns max	$V_s = 3 V$ , see Figure 18
Break-Before-Make Time Delay, $t_{\text{BBM}}$	5			ns typ	$R_L = 50 \Omega$ , $C_L = 35 pF$ , $V_{51} = V_{52} = 3 V$ , see Figure 19
			1	ns min	
Charge Injection	50			pC typ	$V_s = 0 V$ , $R_s = 0 \Omega$ , $C_L = 1 nF$ , see Figure 20
Off Isolation	-64			dB typ	$R_L = 50 \Omega$ , $C_L = 5 pF$ , $f = 100 kHz$ see Figure 21
Channel-to-Channel Crosstalk	-64			dB typ	$R_L = 50 \Omega$ , $C_L = 5 pF$ , $f = 100 kHz$ , see Figure 22
Bandwidth: –3 dB	38			MHz typ	$R_L = 50 \Omega$ , $C_L = 5 pF$ , see Figure 23
Insertion Loss	0.04			dB typ	$R_L = 50 \Omega$ , $C_L = 5 pF$ , see Figure 23
THD + N	0.01			%	$R_{L} = 32 \Omega, f = 20 \text{ Hz to } 20 \text{ kHz},$ Vs = 2 V p-p
C <sub>s</sub> (Off)	52			pF typ	
$C_{\rm D}, C_{\rm S}$ (On)	145			pF typ	
POWER REQUIREMENTS	-			1° 7°	$V_{DD} = 5.5 \text{ V}$ , Digital Inputs = 0 V or 5.5 V
IDD	0.001			μA typ	
				1 m · · · / m	

 $^1 The temperature range for the Y version is -40°C to +125°C. <math display="inline">^2$  Guaranteed by design, not subject to production test.

### Table 2. $V_{DD} = 2.7 \text{ V}$ to 3.6 V, GND = 0 V<sup>1</sup>

Parameter	+25°C	–40°C to +85°C	–40°C to +125°C	Unit	Test Conditions/Comments
ANALOG SWITCH					
Analog Signal Range			$0 V to V_{DD}$	v	
On-Resistance (R <sub>ON</sub> )				Ωtyp	$V_{s} = 0 V \text{ to } V_{DD}$ , $I_{Ds} = -100 \text{ mA}$
	1.1	1.1	1.2	Ωmax	See Figure 15
On-Resistance Match Between Channels $(\Delta R_{ON})$	0.05			Ωtyp	$V_{\rm S} = 1.5 \text{ V}, I_{\rm DS} = -100 \text{ mA}$
	0.095	0.11	0.125	Ωmax	
On-Resistance Flatness (R <sub>FLAT(ON)</sub> )	0.3			Ωtyp	$V_{s} = 0 V \text{ to } V_{DD}$ , $I_{Ds} = -100 \text{ mA}$
LEAKAGE CURRENTS					$V_{DD} = 3.6 V$
Source Off Leakage, Is (Off)	±0.1			nA typ	$V_{s} = 3 V/1 V, V_{D} = 1 V/3 V$ , see Figure 16
Channel On Leakage, $I_D$ , $I_S$ (On)	±0.01			nA typ	$V_S = V_D = 1$ V, or $V_S = V_D = 3$ V; see Figure 17
DIGITAL INPUTS					
Input High Voltage, VINH			2.0	V min	
Input Low Voltage, VINL			0.8	V max	$V_{DD} = 3 V \text{ to } 3.6 V$
			0.7	V max	$V_{DD} = 2.7 V$
Input Current					
	0.005			μA typ	VIN = VINI Or VINH
			±0.1	µA max	
C <sub>IN</sub> , Digital Input Capacitance	2.5			pF typ	
DYNAMIC CHARACTERISTICS <sup>2</sup>	2.0			P: 17P	
ton	16			ns typ	$R_L = 50 \Omega, C_L = 35 pF$
CON	22	24	26	ns max	$V_s = 1.5 V$ , see Figure 18
toff	13		20	ns typ	$R_L = 50 \Omega$ , $C_L = 35 pF$
	18	20	22	ns max	$V_s = 1.5 V$ , see Figure 18
Break-Before-Make Time Delay, $t_{\mbox{\tiny BBM}}$	7	20		ns typ	$R_L = 50 \Omega$ , $C_L = 35 pF$ , $V_{S1} = V_{S2} = 1.5 V$ , see Figure 19
			1	ns min	
Charge Injection	30			pC typ	$V_s = 0 V$ , $R_s = 0 \Omega$ , $C_L = 1 nF$ , see Figure 20
Off Isolation	-64			dB typ	$R_L = 50 \Omega$ , $C_L = 5 pF$ , $f = 100 kHz$ , see Figure 21
Channel-to-Channel Crosstalk	-64			dB typ	$R_L = 50 \Omega$ , $C_L = 5 pF$ , $f = 100 kHz$ , see Figure 22
Bandwidth: –3 dB	38			MHz typ	$R_L = 50 \Omega$ , $C_L = 5 pF$ , see Figure 23
Insertion Loss	0.04			dB typ	$R_L = 50 \Omega C_L = 5 pF$ , see Figure 23
THD + N	0.02			%	$\label{eq:RL} \begin{array}{l} R_{L}=32~\Omega,f=20~Hz~to~20~kHz,\\ Vs=1~V~p\text{-}p \end{array}$
Cs (Off)	55			pF typ	f = 1 MHz
C <sub>D</sub> , C <sub>s</sub> (On)	147			pF typ	f = 1 MHz
POWER REQUIREMENTS					$V_{DD} = 3.6 V$
					Digital Inputs = 0 V or 3.6 V
I <sub>DD</sub>	0.001			µA typ	
			1.0	µA max	

 $^1 The temperature range for the Y version is -40°C to +125°C. <math display="inline">^2$  Guaranteed by design, not subject to production test.

### **ABSOLUTE MAXIMUM RATINGS**

Table 3. $T_A = 25^{\circ}C$ , unless otherwise noted					
Parameter	Rating				
V <sub>DD</sub> to GND	–0.3 V to +7 V				
Analog Inputs <sup>1</sup>	-0.3 V to V <sub>DD</sub> + 0.3 V or 30 mA, whichever occurs first				
Digital Inputs	-0.3 V to V <sub>DD</sub> + 0.3 V or 30 mA, whichever occurs first				
Peak Current, S or D	600 mA (pulsed at 1 ms, 10% duty cycle maximum)				
Continuous Current, S or D	400 mA				
Operating Temperature Range					
Extended	-40°C to +125°C				
Storage Temperature Range	–65°C to +150°C				
Junction Temperature	+150°C				
SC70 Package					
$\theta_{JA}$ Thermal Impedance	332°C/W				
$\theta_{JC}$ Thermal Impedance	120°C/W				
Reflow Soldering					
Peak Temperature	260(0/-5)°C				
Time at Peak Temperature	10 sec to 40 sec				

IN	Switch S1	Switch S2
0	On	Off
1	Off	On

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those listed in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Only one absolute maximum rating may be applied at any one time.

<sup>1</sup> Overvoltages at IN, S, or D will be clamped by internal diodes. Current should be limited to the maximum ratings given.

#### **ESD CAUTION**

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although this product features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



### **PIN CONFIGURATION AND FUNCTION DESCRIPTIONS**

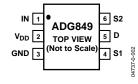


Figure 2. Pin Configuration

#### Table 5. Terminology

Mnemonic	Function
V <sub>DD</sub>	Most Positive Power Supply Potential.
GND	Ground (0 V) Reference.
IDD	Positive Supply Current.
S	Source Terminal. May be an input or output.
D	Drain Terminal. May be an input or output.
IN	Logic Control Input.
Ron	Ohmic Resistance between D and S.
ΔRon	On-Resistance Match Between any Two Channels i.e., Ron Maximum to Ron Minimum.
R <sub>FLAT</sub> (ON)	Flatness is defined as the difference between the maximum and minimum value of on resistance as measured over the specified analog signal range.
Is (Off)	Source Leakage Current with the Switch Off.
I <sub>D</sub> , Is (On)	Channel Leakage Current with the Switch On.
V <sub>D</sub> (V <sub>S</sub> )	Analog Voltage on Terminals D, S.
VINL	Maximum Input Voltage for Logic 0.
V <sub>INH</sub>	Minimum Input Voltage for Logic 1.
I <sub>INL</sub> (I <sub>INH</sub> )	Input Current of the Digital Input.
C <sub>s</sub> (Off)	Off Switch Source Capacitance. Measured with reference to ground.
C <sub>D</sub> , C <sub>S</sub> (On)	On Switch Capacitance. Measured with reference to ground.
t <sub>on</sub>	Delay time between the 50% and 90% points of the digital input and switch on condition.
toff	Delay time between the 50% and 90% points of the digital input and switch off condition.
t <sub>BBM</sub>	On or off time measured between the 80% points of both switches when switching from one to another.
Charge Injection	A measure of the glitch impulse transfered from the digital input to the analog output during switching.
Crosstalk	A measure of unwanted signal that is coupled through from one channel to another as a result of parasitic capacitance.
Off Isolation	A measure of unwanted signal coupling through an off switch.
Bandwidth	The frequency at which the output is attenuated by 3 dB.
On-Response	The frequency response of the on switch.
Insertion Loss	The loss due to the on-resistance of the switch.
THD + N	The ratio of harmonic amplitudes plus the noise of a signal to the fundamental.

### **TYPICAL PERFORMANCE CHARACTERISTICS**

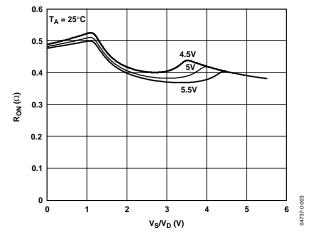


Figure 3. On-Resistance vs.  $V_D/V_{s}$ ,  $V_{DD} = 5 V \pm 10\%$ 

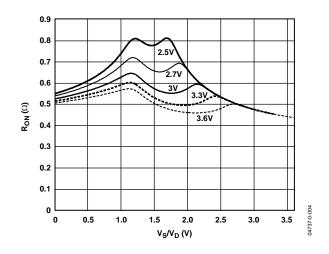


Figure 4. On-Resistance vs.  $V_D/V_s$ ,  $V_{DD} = 2.5 V$  to 3.6 V

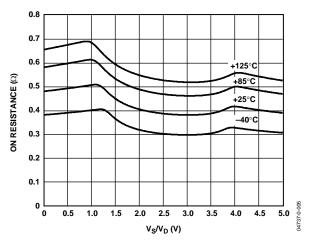


Figure 5. On-Resistance vs. Temperature,  $V_{DD} = 5 V$ 

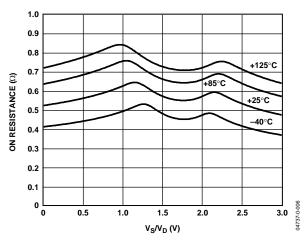


Figure 6. On-Resistance vs. Temperature,  $V_{DD} = 3 V$ 

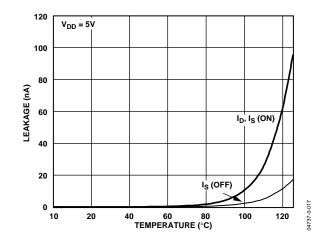


Figure 7. Leakage Currents vs. Temperature,  $V_{DD} = 5 V$ 

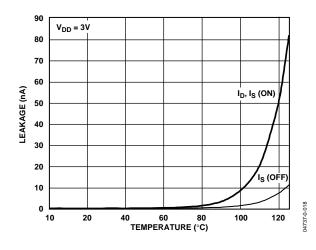
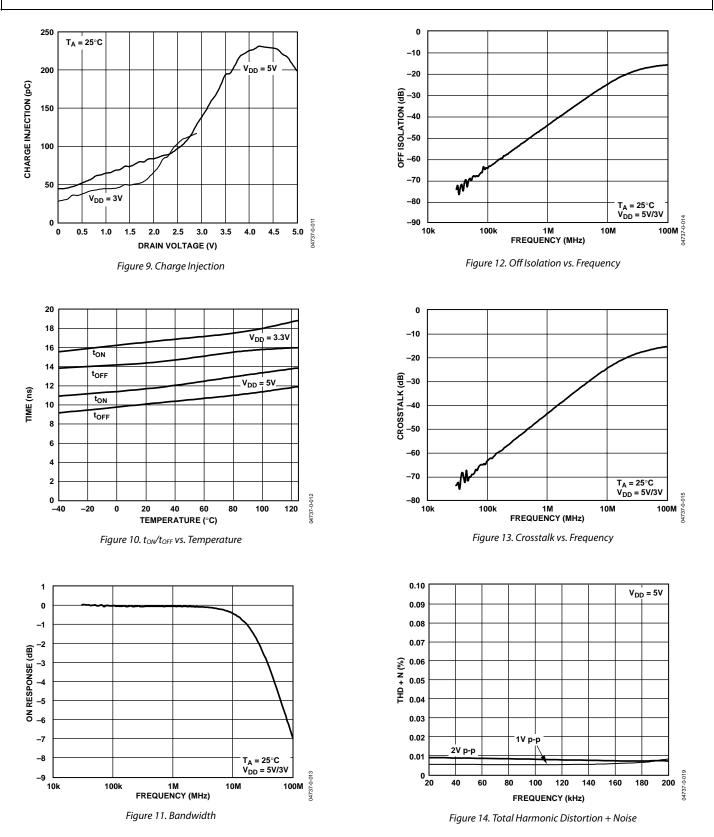
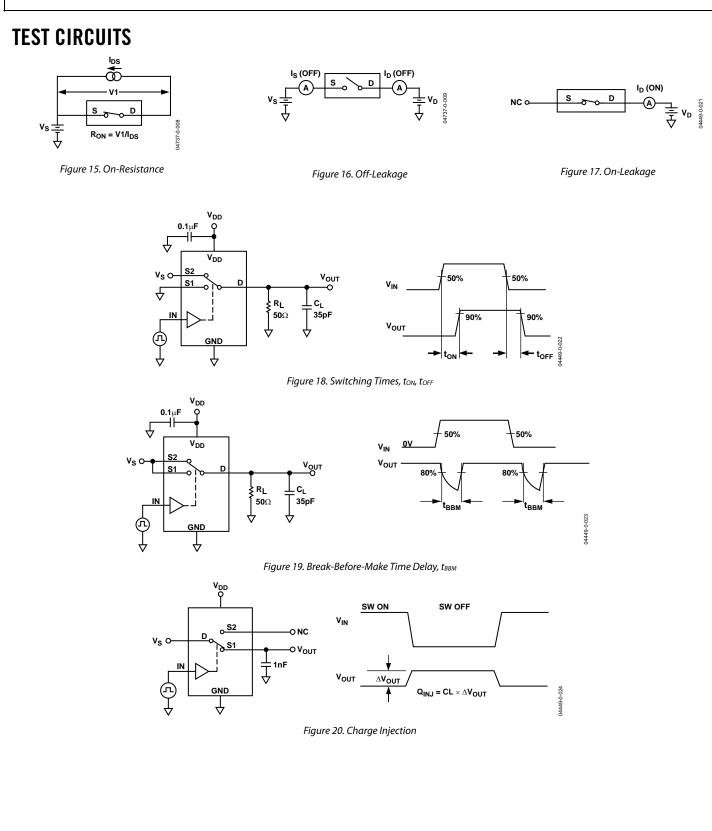


Figure 8. Leakage Currents vs. Temperature,  $V_{DD} = 3 V$ 





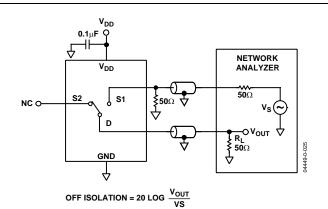


Figure 21. Off Isolation

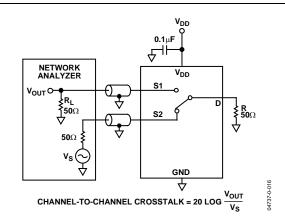
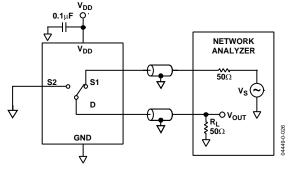


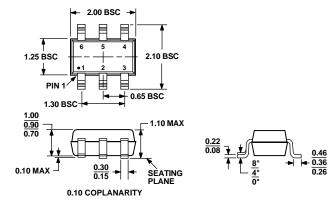
Figure 22. Channel-to-Channel Crosstalk



INSERTION LOSS = 20 LOG  $\frac{V_{OUT} \text{ WITH SWITCH}}{V_{OUT} \text{ WITHOUT SWITCH}}$ 

Figure 23. Bandwidth

### **OUTLINE DIMENSIONS**



COMPLIANT TO JEDEC STANDARDS MO-203AB

Figure 24. 6-Lead SC70 Package [KS-6] Dimensions shown in Millimeters

#### **ORDERING GUIDE**

Model	Temperature Range	Package Description	Package Option	Branding <sup>1</sup>
ADG849YKSZ-500RL7 <sup>2</sup>	–40°C to +125°C	SC70 (Plastic Surface Mount)	KS-6	SNA
ADG849YKSZ-REEL <sup>2</sup>	-40°C to +125°C	SC70 (Plastic Surface Mount)	KS-6	SNA
ADG849YKSZ-REEL7 <sup>2</sup>	–40°C to +125°C	SC70 (Plastic Surface Mount)	KS-6	SNA

 $^{\rm 1}$  Branding on all packages is limited to three characters due to space constraints.  $^{\rm 2}$  Z = Pb-free part.

### NOTES



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Rev. 0| Page 12 of 12

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